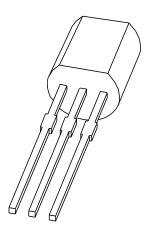
## **DISCRETE SEMICONDUCTORS**

# DATA SHEET



## BB204B; BB204G VHF variable capacitance double diodes

Product specification
Supersedes data of April 1992
File under Discrete Semiconductors, SC01

1996 May 03





Philips Semiconductors Product specification

## VHF variable capacitance double diodes

BB204B; BB204G

#### **FEATURES**

- · Selected capacitance ranges
- Leaded plastic package
- C30: 14 pF; ratio: 2.6.

#### **APPLICATIONS**

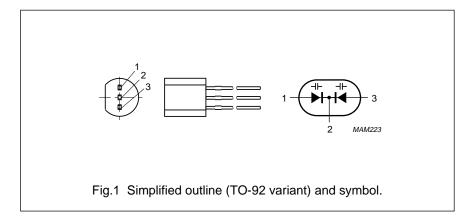
- Electronic tuning in FM radio applications
- VCO.

#### **DESCRIPTION**

The BB204B, BB204G are variable capacitance double diodes with common cathodes, fabricated in planar technology, and encapsulated in TO-92 variant leaded plastic packages.

#### **PINNING**

PIN	DESCRIPTION
1	anode (a1)
2	common cathode
3	anode (a2)



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT		
Per diode						
V <sub>R</sub>	continuous reverse voltage	_	30	V		
I <sub>F</sub>	continuous forward current		100	mA		
T <sub>stg</sub>	T <sub>stg</sub> storage temperature		+100	°C		
Tj	operating junction temperature	<b>-55</b>	+100	°C		

1996 May 03 2

Philips Semiconductors Product specification

## VHF variable capacitance double diodes

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#### **ELECTRICAL CHARACTERISTICS**

 $T_j = 25$  °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Per diode							
I <sub>R</sub>	reverse current	V <sub>R</sub> = 30 V; see Fig.3	_	_	50	nA	
		V <sub>R</sub> = 30 V; T <sub>j</sub> = 85 °C; see Fig.3	_	_	300	nA	
r <sub>s</sub>	diode series resistance	f = 100 MHz; note 1	_	0.2	0.4	Ω	
C <sub>d</sub>	diode capacitance	see Figs 2 and 4					
	BB204B	V <sub>R</sub> = 3 V; f = 1 MHz	37	_	42	pF	
		V <sub>R</sub> = 8 V; f = 1 MHz	24	_	29	pF	
		V <sub>R</sub> = 30 V; f = 1 MHz	_	14	_	pF	
	BB204G	V <sub>R</sub> = 3 V; f = 1 MHz	34	_	39	pF	
		V <sub>R</sub> = 8 V; f = 1 MHz	22	_	27	pF	
		V <sub>R</sub> = 30 V; f = 1 MHz	_	14	_	pF	
C <sub>d(3V)</sub>	capacitance ratio	f = 1 MHz	2.5	_	2.8		
C <sub>d (30V)</sub>							

#### Note

1996 May 03 3

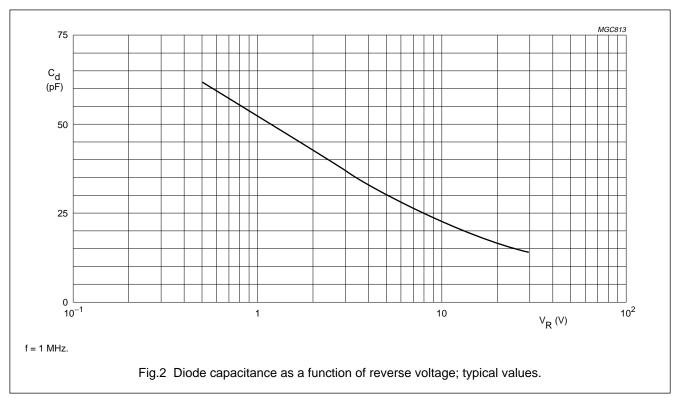
<sup>1.</sup>  $V_R$  is the value at which  $C_d = 38$  pF.

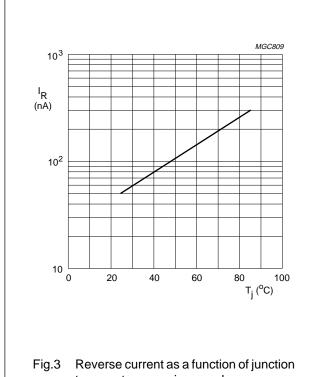
Philips Semiconductors Product specification

## VHF variable capacitance double diodes

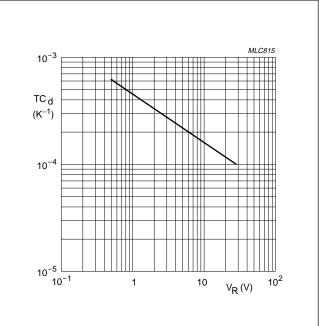
BB204B; BB204G

#### **GRAPHICAL DATA**





temperature; maximum values.



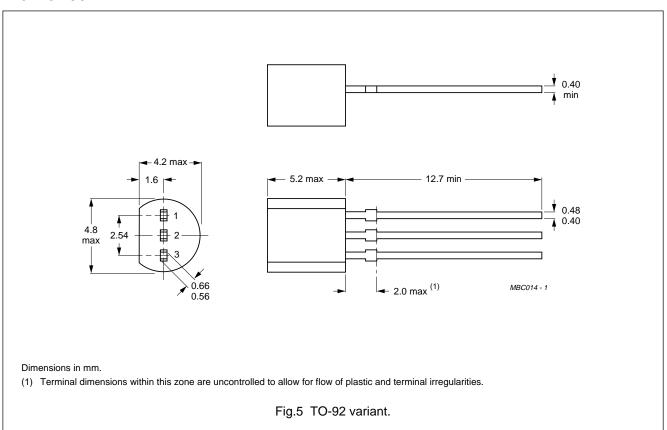
Temperature coefficient of diode capacitance as a function of reverse voltage; typical values.

Philips Semiconductors Product specification

### VHF variable capacitance double diodes

BB204B; BB204G

#### **PACKAGE OUTLINE**



#### **DEFINITIONS**

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

#### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

1996 May 03 5